

TPS2110A TPS2111A

SBVS043 - MARCH 2004

AUTOSWITCHING POWER MUX

FEATURES

- Two-Input, One-Output Power Multiplexer With Low r_{DS(on)} Switches:
 - 84 mΩ Typ (TPS2111A)
 - 120 mΩ Typ (TPS2110A)
- Reverse and Cross-Conduction Blocking
- Wide Operating Voltage Range2.8 V to 5.5 V
- Low Standby Current 0.5-μA Typ
- Low Operating Current 55-μA Typ
- Adjustable Current Limit
- Controlled Output Voltage Transition Times, Limits Inrush Current and Minimizes Output Voltage Hold-Up Capacitance
- CMOS- and TTL-Compatible Control Inputs
- Manual and Auto-Switching Operating Modes
- Thermal Shutdown
- Available in a TSSOP-8 Package

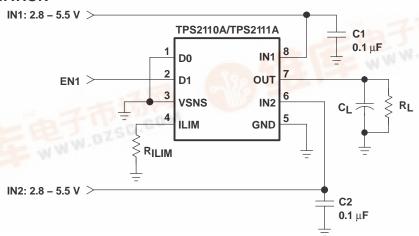
APPLICATIONS

- PCs
- PDAs
- Digital Cameras
- Modems
- Cell Phones
- Digital Radios
- MP3 Players

DESCRIPTION

The TPS211xA family of power multiplexers enables seamless transition between two power supplies, such as a battery and a wall adapter, each operating at 2.8–5.5 V and delivering up to 1 A. The TPS211xA family includes extensive protection circuitry, including user-programmable current limiting, thermal protection, inrush current control, seamless supply transition, cross-conduction blocking, and reverse-conduction blocking. These features greatly simplify designing power multiplexer applications.

TYPICAL APPLICATION



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SBVS043 - MARCH 2004





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

AVAILABLE OPTIONS

FEATURE		TPS2110A	TPS2111A	TPS2112A	TPS2113A	TPS2114A	TPS2115A
Current Limit Adjustment Range		0.31-0.75A	0.63-1.25A	0.31-0.75A	0.63-1.25A	0.31-0.75A	0.63-1.25A
Switching Modes	Manual	Yes	Yes	No	No	Yes	Yes
Switching Modes	Automatic	Yes	Yes	Yes	Yes	Yes	Yes
Switch Status Output		No	No	Yes	Yes	Yes	Yes
Package		TSSOP-8	TSSOP-8	TSSOP-8	TSSOP-8	TSSOP-8	TSSOP-8

ORDERING INFORMATION

TA	PACKAGE	ORDERING NUMBER ⁽¹⁾ MARKINGS			
4000 to 0500	TOOOD O (DIA)	TPS2110APW	2110A		
-40°C to 85°C	TSSOP-8 (PW)	TPS2111APW	2111A		

⁽¹⁾ The PW package is available taped and reeled. Add an **R** suffix to the device type (e.g., TPS2110APWR) to indicate tape and reel.

PACKAGE DISSIPATION RATINGS

PACKAGE	DERATING FACTOR ABOVE $T_A = 25^{\circ}C$	$T_{\mbox{\scriptsize A}} \le 25^{\circ}\mbox{\scriptsize C}$ POWER RATING	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING
TSSOP-8 (PW)	3.9 mW/°C	387 mW	213 mW	155 mW

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range unless otherwise noted(1)

		TPS2110A, TPS2111A
Input voltage range at pins IN1, IN2,	D0, D1, VSNS, ILIM(2)	-0.3 V to 6 V
Output voltage range, VO(OUT)(2)		-0.3 V to 6 V
Continuous subsut surrent L-	TPS2110A	0.9 A
Continuous output current, I _O	TPS2111A	1.5 A
Continuous total power dissipation		See Dissipation Rating Table
Operating virtual junction temperature	e range, TJ	-40°C to 125°C
Storage temperature range, T _{Stg}		−65°C to 150°C
Lead temperature soldering 1,6 mm (1/16 inch) from case for 10 seconds	260°C

⁽¹⁾ Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

		MI	N MAX	UNIT
Leaved and line and third Ad	V _{I(IN2)} ≥ 2.8 V	1.	5 5.5	
Input voltage at IN1, V _{I(IN1)}	V _{I(IN2)} < 2.8 V	2	8 5.5	_ V
Lead value at INO V	V _{I(IN1)} ≥ 2.8 V	1.	1.5 5.5 2.8 5.5	
Input voltage at IN2, V _{I(IN2)}	V _{I(IN1)} < 2.8 V	2	8 5.5	_ V
Input voltage, VI(DO), VI(D1), VI(VSNS)			0 5.5	V
	TPS2110A	0.3	1 0.75	
Current limit adjustment range, IO(OUT)	TPS2111A	0.6	3 1.25	A
Operating virtual junction temperature, TJ		-4	0 125	°C

ELECTROSTATIC DISCHARGE (ESD) PROTECTION

	MIN	MAX	UNIT
Human body model		2	kV
CDM		500	V

⁽²⁾ All voltages are with respect to GND.



ELECTRICAL CHARACTERISTICS

over recommended operating junction temperature range, $V_{I(IN1)} = V_{I(IN2)} = 5.5 \text{ V}$, $R_{ILIM} = 400 \Omega$ (unless otherwise noted)

PARAMETER					TPS2110A		TPS2111A			
		TEST CONDITIONS		MIN	TYP	MAX	MIN	TYP	MAX	UNIT
POWER SV	VITCH									
	Drain-source 1) on-state resistance (INx–OUT)	$T_{J} = 25^{\circ}C,$ $I_{L} = 500 \text{ mA}$ $T_{J} = 125^{\circ}C,$ $I_{I} = 500 \text{ mA}$	$V_{I(IN1)} = V_{I(IN2)} = 5.0 \text{ V}$		120	140		84	110	
			$V_{I(IN1)} = V_{I(IN2)} = 3.3 \text{ V}$		120	140		84	110	$m\Omega$
r= - (1)			$V_{I(IN1)} = V_{I(IN2)} = 2.8 \text{ V}$		120	140		84	110	
rDS(on) ⁽¹⁾			$V_{I(IN1)} = V_{I(IN2)} = 5.0 \text{ V}$			220			150	
	/		$V_{I(IN1)} = V_{I(IN2)} = 3.3 \text{ V}$			220			150	$m\Omega$
		IL - 000 IIIA	$V_{I(IN1)} = V_{I(IN2)} = 2.8 \text{ V}$			220			150	

⁽¹⁾ The TPS211xA can switch a voltage as low as 1.5 V as long as there is a minimum of 2.8 V at one of the input power pins. In this specific case, the lower supply voltage has no effect on the IN1 and IN2 switch on-resistances.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
LOGIC INPUTS (D0 AND D1)					
VIH High-level input voltage		2			V
V _{IL} Low-level input voltage				0.7	V
lanut ourrent at D0 or D1	D0 or D1 = High, sink current			1	^
Input current at D0 or D1	D0 or D1 = Low, source current	0.5	1.4	5	μΑ
SUPPLY AND LEAKAGE CURRE	NTS				
	D1 = High, D0 = Low (IN1 active), $V_{I(IN1)}$ = 5.5 V, $V_{I(IN2)}$ = 3.3 V, $I_{O(OUT)}$ = 0 A		55	90	
Supply current from IN1	D1 = High, D0 = Low (IN1 active), $V_{I(IN1)}$ = 3.3 V, $V_{I(IN2)}$ = 5.5 V, $I_{O(OUT)}$ = 0 A		1	12	^
(operating)	D0 = D1 = Low (IN2 active), $V_{I(IN1)} = 5.5 \text{ V}$, $V_{I(IN2)} = 3.3 \text{ V}$, $I_{O(OUT)} = 0 \text{ A}$			75	μΑ
	D0 = D1 = Low (IN2 active), $V_{I(IN1)}$ = 3.3 V, $V_{I(IN2)}$ = 5.5 V, $I_{O(OUT)}$ = 0 A			1	
	D1 = High, D0 = Low (IN1 active), $V_{I(IN1)}$ = 5.5 V, $V_{I(IN2)}$ = 3.3 V, $I_{O(OUT)}$ = 0 A			1	
Supply current from IN2	D1 = High, D0 = Low (IN1 active), $V_{I(IN1)} = 3.3 \text{ V}$, $V_{I(IN2)} = 5.5 \text{ V}$, $I_{O(OUT)} = 0 \text{ A}$			75	
(operating)	$D0 = D1 = Low (IN2 active), V_{I(IN1)} = 5.5 V, V_{I(IN2)} = 3.3 V, I_{O(OUT)} = 0 A$		1	12	μΑ
	$D0 = D1 = Low (IN2 active), V_{I(IN1)} = 3.3 V, V_{I(IN2)} = 5.5 V, I_{O(OUT)} = 0 A$		55	90	
Quiescent current from IN1	D0 = D1 = High (inactive), $V_{I(IN1)} = 5.5 \text{ V}$, $V_{I(IN2)} = 3.3 \text{ V}$, $I_{O(OUT)} = 0 \text{ A}$		0.5	2	^
(STANDBY)	D0 = D1 = High (inactive), $V_{I(IN1)}$ = 3.3 V, $V_{I(IN2)}$ = 5.5 V, $I_{O(OUT)}$ = 0 A			1	μΑ
Quiescent current from IN2	D0 = D1 = High (inactive), $V_{I(IN1)} = 5.5 \text{ V}$, $V_{I(IN2)} = 3.3 \text{ V}$, $I_{O(OUT)} = 0 \text{ A}$			1	4
(STANDBY)	D0 = D1 = High (inactive), $V_{I(IN1)} = 3.3 \text{ V}$, $V_{I(IN2)} = 5.5 \text{ V}$, $V_{I(IN2)} = 5.$		0.5	2	μΑ
Forward leakage current from IN1 (measured from OUT to GND)	D0 = D1 = High (inactive), $V_{I(IN1)}$ = 5.5 V, IN2 open, $V_{O(OUT)}$ = 0 V (shorted), T_{J} = 25°C		0.1	5	μΑ
Forward leakage current from IN2 (measured from OUT to GND)	D0 = D1 = High (inactive), $V_{I(IN2)}$ = 5.5 V, IN1 open, $V_{O(OUT)}$ = 0 V (shorted), T_J = 25°C		0.1	5	μΑ
Reverse leakage current to INx (measured from INx to GND)	D0 = D1 = High (inactive), $V_{I(INx)} = 0 \text{ V}$, $V_{O(OUT)} = 5.5 \text{ V}$, $T_{J} = 25^{\circ}\text{C}$		0.3	5	μΑ

SBVS043 - MARCH 2004



ELECTRICAL CHARACTERISTICS (Continued)

over recommended operating junction temperature range, $V_{I(IN1)} = V_{I(IN2)} = 5.5 \text{ V}$, $R_{ILIM} = 400 \Omega$ (unless otherwise noted)

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
CUR	RENT LIMIT CIRCUIT						
	TPS2110A	R _{ILIM} = 400 Ω	0.51	0.63	0.80		
	Owner of Parity and a second	1P52110A	R _{ILIM} = 700 Ω	0.30	0.36	0.50	٨
	Current limit accuracy	TPS2111A	R _{ILIM} = 400 Ω	0.95	1.25	1.56	Α
		IPSZIIIA	R _{ILIM} = 700 Ω	0.47	0.71	0.99	
t _d	Current limit settling time(1)		Time for short-circuit output current to settle within 10% of its steady state value.		1		ms
	Input current at ILIM		$V_{I(ILIM)} = 0 \text{ V}, I_{O(OUT)} = 0 \text{ A}$	-15		0	μА

⁽¹⁾ Not tested in production.

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
VSNS COMPARATOR					
VONO three-baldwelters	V _I (VSNS) ↑	0.78	0.8	0.82	.,
VSNS threshold voltage	V _I (VSNS) ↓	0.735	0.755	0.775	V
VSNS comparator hysteresis(1)		30		60	mV
Deglitch of VSNS comparator (both ↑↓)(1)		90	150	220	μs
Input current	0 V ≤ V _I (VSNS) ≤ 5.5 V	-1		1	μΑ
UVLO					
INTO A STATE OF THE STATE OF TH	Falling edge	1.15	1.25		.,
IN1 and IN2 UVLO	Rising edge		1.30	1.35	V
IN1 and IN2 UVLO hysteresis ⁽¹⁾		30	57	65	mV
	Falling edge	2.4	2.53		.,
Internal V _{DD} UVLO (the higher of IN1 and IN2)	Rising edge		2.58	2.8	V
Internal V _{DD} UVLO hysteresis(1)		30	50	75	mV
UVLO deglitch for IN1, IN2 ⁽¹⁾	Falling edge		110		μs

⁽¹⁾ Not tested in production.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
REVERSE CO	NDUCTION BLOCKING					
ΔVO(I_block)	Minimum output-to-input voltage difference to block switching	D0 = D1 = high, $V_{I(INX)} = 3.3 \text{ V}$. Connect OUT to a 5 V supply through a series 1- $\kappa\Omega$ resistor. Let D0 = low. Slowly decrease the supply voltage until OUT connects to IN1.	80	100	120	mV

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
THERMAL SHUTDOWN					
Thermal shutdown threshold ⁽¹⁾	TPS211xA is in current limit.	135			
Recovery from thermal shutdown ⁽¹⁾	TPS211xA is in current limit.	125			°C
Hysteresis ⁽¹⁾			10		
IN2-IN1 COMPARATORS					
Hysteresis of IN2–IN1 comparator		0.1		0.2	V
Deglitch of IN2–IN1 comparator (both ↑↓)(1)		10	20	50	μs

⁽¹⁾ Not tested in production.

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SWITCHING CHARACTERISTICS

over recommended operating junction temperature range, $V_{I(IN1)} = V_{I(IN2)} = 5.5 \text{ V}$, $R_{ILIM} = 400 \Omega$ (unless otherwise noted)

				TI	TPS2110A			TPS2111A		
	PARAMETER	TEST CO	NDITIONS	MIN TYP MAX			MIN	TYP	MAX	UNIT
POWE	POWER SWITCH									
t _r	Output rise time from an enable(1)	VI(IN1) = VI(IN2) = 5 V	$T_J = 25^{\circ}C$, $C_L = 1 \mu F$, $I_L = 500 \text{ mA}$, See Figure 1(a)	0.5	1.0	1.5	1	1.8	3	ms
tf	Output fall time from a disable(1)	VI(IN1) = VI(IN2) = 5 V	$T_J = 25^{\circ}C$, $C_L = 1 \mu F$, $I_L = 500 \text{ mA}$, See Figure 1(a)	0.35	0.5	0.7	0.5	1	2	ms
tt	Transition time(1)	IN1 to IN2 transition, VI(IN1) = 3.3 V, VI(IN2) = 5 V	$T_J = 125^{\circ}C$, $C_L = 10 \mu F$, $I_L = 500 \text{ mA}$ [Measure transition time		40	60		40	60	
		IN2 to IN1 transition, V _I (IN1) = 5 V, V _I (IN2) = 3.3 V	as 10–90% rise time or from 3.4 V to 4.8 V on VO(OUT)], See Figure 1(b)		40	60		40	60	μs
^t PLH1	Turn-on propagation delay from enable(1)	V _{I(IN1)} = V _{I(IN2)} = 5 V Measured from enable to 10% of V _{O(OUT)}	$T_J = 25^{\circ}C, C_L = 10 \mu F,$ $I_L = 500 \text{ mA},$ See Figure 1(a)		0.5			1		ms
^t PHL1	Turn-off propagation delay from a disable ⁽¹⁾	$V_{I(IN1)} = V_{I(IN2)} = 5 \text{ V},$ Measured from disable to 90% of $V_{O(OUT)}$	$T_J = 25^{\circ}C, C_L = 10 \mu F,$ $I_L = 500 \text{ mA},$ See Figure 1(a)		3			5		ms
^t PLH2	Switch-over rising propagation delay(1)	Logic 1 to Logic 0 transition on D1, VI(IN1) = 1.5 V, VI(IN2) = 5 V, VI(D0) = 0 V, Measured from D1 to 10% of VO(OUT)	$T_J = 25^{\circ}C$, $C_L = 10 \mu F$, $I_L = 500 \text{ mA}$, See Figure 1(c)		40	100		40	100	μs
[†] PHL2	Switch-over falling propagation delay(1)	Logic 0 to Logic 1 transition on D1, VI(IN1) = 1.5V, VI(IN2) = 5V, VI(D0) = 0 V, Measured from D1 to 90% of VO(OUT)	$T_J = 25$ °C, $C_L = 10 \mu F$, $I_L = 500 \text{ mA}$, See Figure 1(c)	2	3	10	2	5	10	ms

⁽¹⁾ Not tested in production.



TRUTH TABLE

D1	D0	V _{I(VSNS)} > 0.8V	V _{I(IN2)} > V _{I(IN1)}	OUT(1)
0	0	X	X	IN2
0	1	YES	X	IN1
0	1	NO	NO	IN1
0	1	NO	YES	IN2
1	0	X	X	IN1
1	1	Х	X	Hi-Z

X = Don't care.

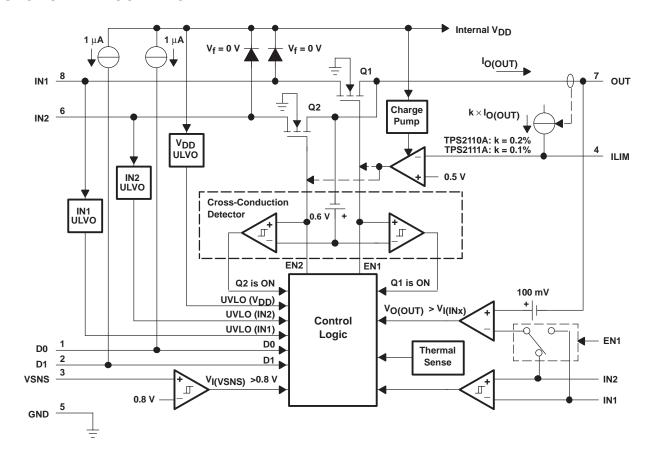
Terminal Functions

TERMINAL									
NAME	NO.	1/0	DESCRIPTION						
D0	1	I	TTL- and CMOS-compatible input pins. Each pin has a 1-μA pull-up. The truth table shown above illustrates the						
D1	2	- 1	functionality of D0 and D1.						
GND	5	- 1	Ground						
IN1	8	I	Primary power switch input. The IN1 switch can be enabled only if the IN1 supply is above the UVLO threshold and at least one supply exceeds the internal V _{DD} UVLO.						
IN2	6	I	Secondary power switch input. The IN2 switch can be enabled only if the IN2 supply is above the UVLO threshold and at least one supply exceeds the internal V _{DD} UVLO.						
ILIM	4	I	A resistor R _{ILIM} from ILIM to GND sets the current limit I _L to 250/R _{ILIM} and 500/R _{ILIM} for the TPS2110A and TPS2111A, respectively.						
OUT	7	0	Power switch output						
VSNS	3	Ţ	In the auto-switching mode (D0 = 1, D1 = 0), an internal power FET connects OUT to IN1 if the VSNS voltage is greater than 0.8 V. Otherwise, the FET connects OUT to the higher of IN1 and IN2. The truth table shown above illustrates the functionality of VSNS.						

⁽¹⁾The under-voltage lockout circuit causes the output to go Hi-Z if the selected power supply does not exceed the IN1/IN2 UVLO, or if neither of the supplies exceeds the internal VDD UVLO.

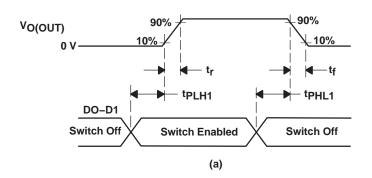


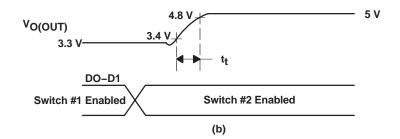
FUNCTIONAL BLOCK DIAGRAM





PARAMETER MEASUREMENT INFORMATION





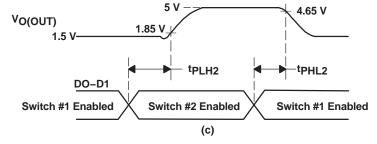


Figure 1. Propagation Delays and Transition Timing Waveforms

8



OUTPUT SWITCHOVER RESPONSE

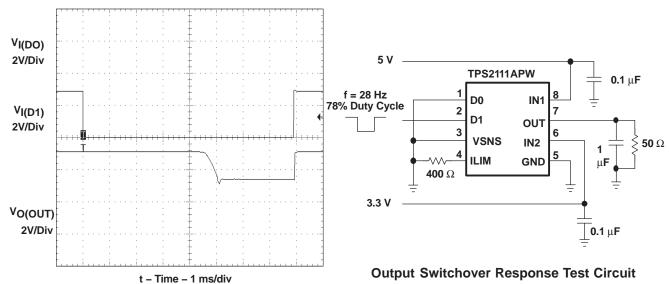


Figure 2

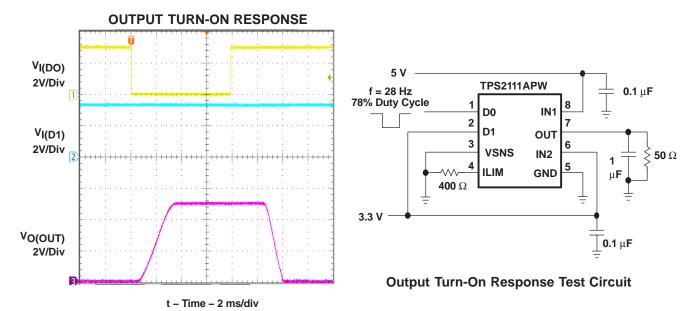


Figure 3



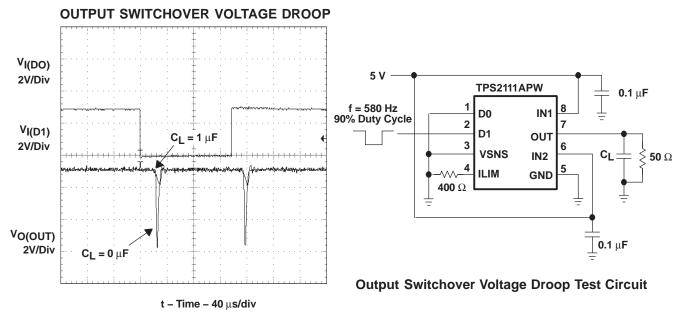
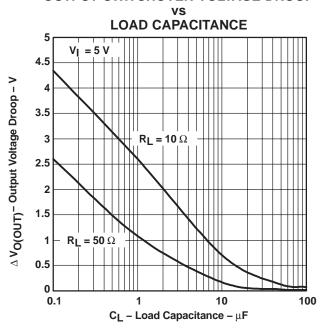
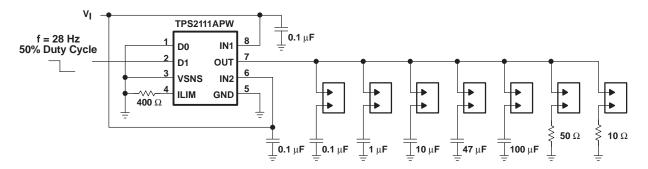


Figure 4



OUTPUT SWITCHOVER VOLTAGE DROOP

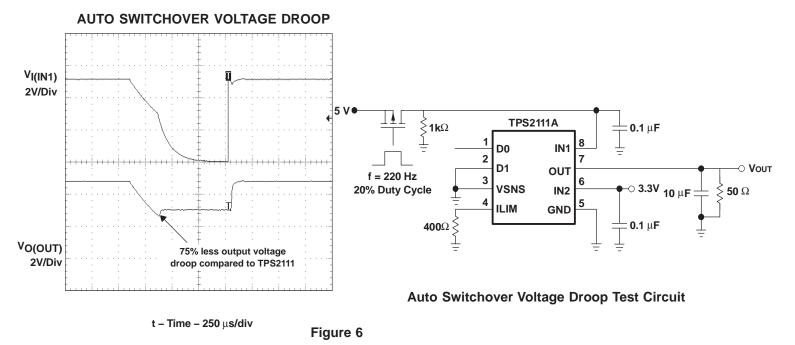




Output Switchover Voltage Droop Test Circuit

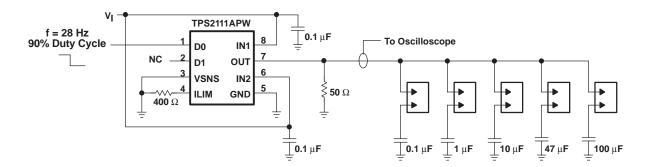
Figure 5







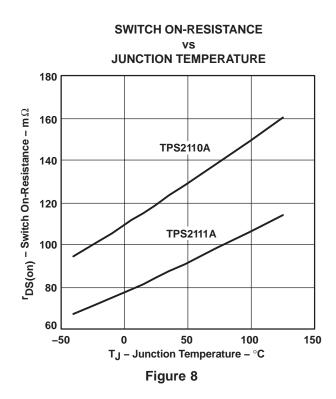
INRUSH CURRENT LOAD CAPACITANCE 300 250 I - Inrush Current - mA 200 $V_I = 5 \text{ V}$ 150 $V_I = 3.3 V$ 100 50 0 0 40 80 100 C_L – Load Capacitance – μF

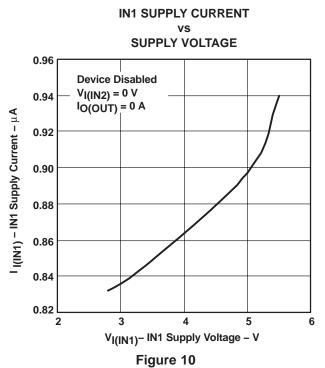


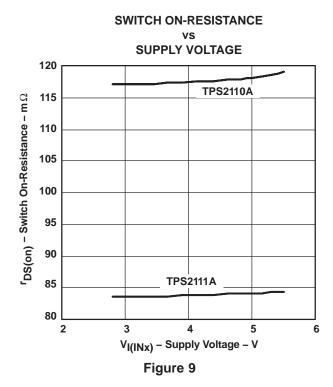
Output Capacitor Inrush Current Test Circuit

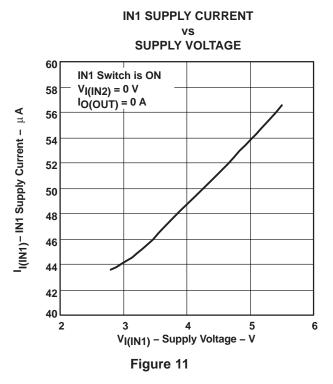
Figure 7



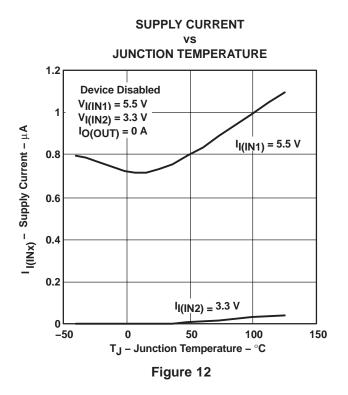


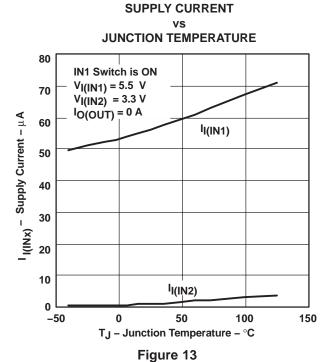














APPLICATION INFORMATION

Some applications have two energy sources, one of which should be used in preference to another. Figure 14 shows a circuit that will connect IN1 to OUT until the voltage at IN1 falls below a user-specified value. Once the voltage on IN1 falls below this value, the TPS211xA will select the higher of the two supplies. This usually means that the TPS211xA will swap to IN2.

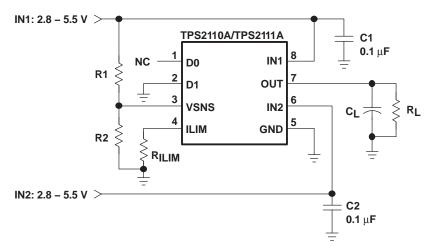


Figure 14. Auto-Selecting for a Dual Power Supply Application

In Figure 15, the multiplexer selects between two power supplies based upon the EN1 logic signal. OUT connects to IN1 if EN1 is logic 1; otherwise, OUT connects to IN2. The logic thresholds for the D1 terminal are compatible with both TTL and CMOS logic.

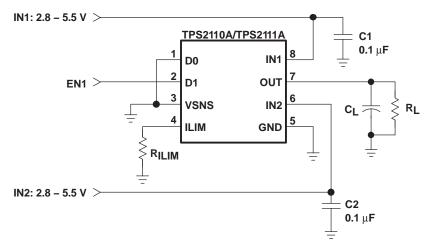


Figure 15. Manually Switching Power Sources



DETAILED DESCRIPTION

AUTO-SWITCHING MODE

D0 equal to logic 1 and D1 equal to logic 0 selects the auto-switching mode. In this mode, OUT connects to IN1 if $V_{I(VSNS)}$ is greater than 0.8 V, otherwise OUT connects to the higher of IN1 and IN2.

The VSNS terminal includes hysteresis equal to 3.75–7.5% of the threshold selected for transition from the primary supply to the higher of the two supplies. This hysteresis helps avoid repeated switching from one supply to the other due to resistive drops.

MANUAL SWITCHING MODE

D0 equal to logic 0 selects the manual-switching mode. In this mode, OUT connects to IN1 if D1 is equal to logic 1, otherwise OUT connects to IN2.

N-CHANNEL MOSFETs

Two internal high-side power MOSFETs implement a single-pole double-throw (SPDT) switch. Digital logic selects the IN1 switch, IN2 switch, or no switch (Hi-Z state). The MOSFETs have no parallel diodes so output-to-input current cannot flow when the FET is off. An integrated comparator prevents turn-on of a FET switch if the output voltage is greater than the input voltage.

CROSS-CONDUCTION BLOCKING

The switching circuitry ensures that both power switches will never conduct at the same time. A comparator monitors the gate-to-source voltage of each power FET and allows a FET to turn on only if the gate-to-source voltage of the other FET is below the turn-on threshold voltage.

REVERSE-CONDUCTION BLOCKING

When the TPS211xA switches from a higher-voltage supply to a lower-voltage supply, current can potentially flow back from the load capacitor into the lower-voltage supply. To minimize such reverse conduction, the TPS211xA will not connect a supply to the output until the output voltage has fallen to within 100 mV of the supply voltage. Once a supply has been connected to the output, it will remain connected regardless of output voltage.

CHARGE PUMP

The higher of supplies IN1 and IN2 powers the internal charge pump. The charge pump provides power to the current limit amplifier and allows the output FET gate voltage to be higher than the IN1 and IN2 supply voltages. A gate voltage that is higher than the source voltage is necessary to turn on the N-channel FET.

CURRENT LIMITING

A resistor R_{ILIM} from ILIM to GND sets the current limit to $250/R_{ILIM}$ and $500/R_{ILIM}$ for the TPS2110A and TPS2111A, respectively. Setting resistor R_{ILIM} equal to zero is not recommended as that disables current limiting.

OUTPUT VOLTAGE SLEW-RATE CONTROL

The TPS211xA slews the output voltage at a slow rate when OUT switches to IN1 or IN2 from the Hi-Z state (see *Truth Table*). A slow slew rate limits the inrush current into the load capacitor. High inrush currents can glitch the voltage bus and cause a system to hang up or reset. It can also cause reliability issues—like pit the connector power contacts, when hot-plugging a load such as a PCI card. The TPS211xA slews the output voltage at a much faster rate when OUT switches between IN1 and IN2. The fast rate minimizes the output voltage droop and reduces the output voltage hold-up capacitance requirement.



PACKAGE OPTION ADDENDUM

14-Mar-2006

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TPS2110APW	ACTIVE	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2110APWG4	ACTIVE	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2110APWR	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2110APWRG4	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2111APW	ACTIVE	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2111APWG4	ACTIVE	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2111APWR	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS2111APWRG4	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153

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